

IGBT MODULE (L series)

■ Features

- High Speed Switching
- Low Saturation Voltage
- Voltage Drive

■ Applications

- Inverter for Motor Drive
- AC and DC Servo Drive Amplifier
- Uninterruptible Power Supply
- Industrial Machines, such as Welding Machines

■ Maximum Ratings and Characteristics

● Absolute Maximum Ratings

Items	Symbols	Ratings	Units
Collector-Emitter Voltage	V _{CES}	600	V
Gate-Emitter Voltage	V _{GES}	±20	V
Collector Current	Continuous	I _c	400
	1ms	I _{c pulse}	800
	Continuous	-I _c	400
	1ms	-I _{c pulse}	800
Max. Power Dissipation	P _c	1600	W
Operating Temperature	T _j	+150	°C
Storage Temperature	T _{stg}	-40 to +125	°C
Isolation Voltage	AC. 1min.	V _{is}	2500
Screw Torque	Mounting *1	3.5	N•m
	Terminals *2	4.5	

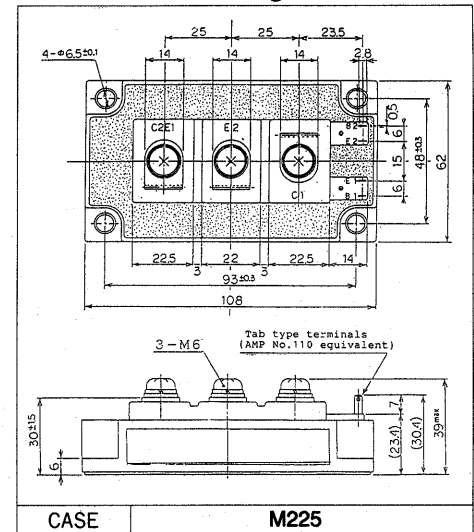
● Electrical Characteristics (T_j=25°C)

Items	Symbols	Test Conditions	Min.	Typ.	Max.	Units
Zero Gate Voltage Collector Current	I _{CES}	V _{GE} =0V V _{CE} =600V T _j =25°C			4.0	mA
Gate-Emitter Leakage Current	I _{GES}	V _{CE} =0V V _{GE} =±20V			400	nA
Gate-Emitter Threshold Voltage	V _{GE(th)}	V _{CE} =20V I _c =400mA	3.0		6.0	V
Collector-Emitter Saturation Voltage	V _{CE(sat)}	V _{GE} =15V I _c =400A		2.7	3.5	V
Input Capacitance	C _{ies}	V _{GE} =0V		38000		pF
Output Capacitance	C _{oes}	V _{CE} =10V		-		
Reverse Transfer Capacitance	C _{res}	f=1MHz		-		
Turn-on Time	t _{on}	V _{CC} =300V		0.6	0.8	μs
	t _r	I _c =400A		0.4	0.6	
Turn-off Time	t _{off}	V _{GE} =±15V		0.7	1.0	
	t _f	R _G =4.7Ω		0.2	0.35	
Diode Forward On-Voltage	V _F	I _F =400A V _{GE} =0V			2.5	V
Reverse Recovery Time	t _{rr}	I _F =400A -di/dt=1200A/μs V _{GE} =-10V			300	ns

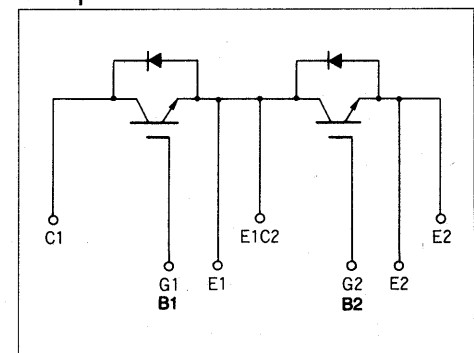
● Thermal Characteristics

Items	Symbols	Test Conditions	Min.	Typ.	Max.	Units
Thermal Resistance	R _{th(j-c)}	IGBT			0.078	°C/W
	R _{th(j-e)}	Diode			0.15	
	R _{th(c-f)}	With Thermal compound		0.0125		

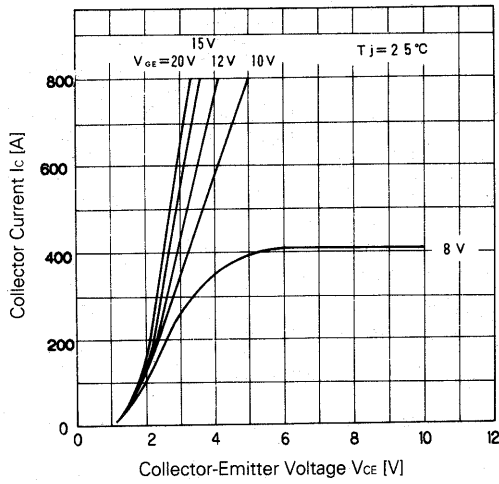
■ Outline Drawings



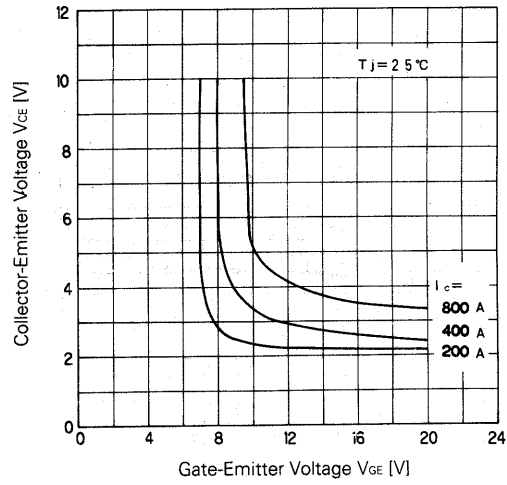
■ Equilavent Circuit Schematic



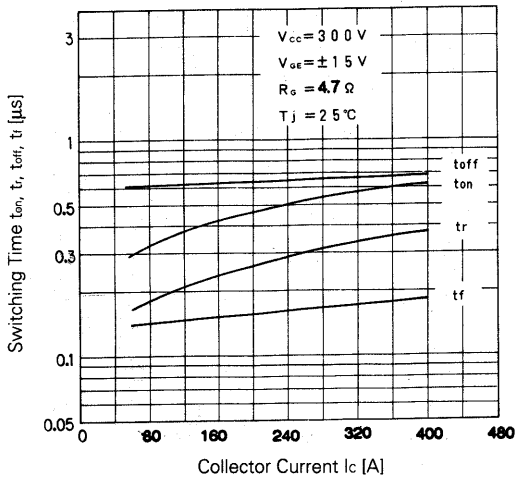
- *1 Recommendable Value 2.5 ~ 3.5 N•m (M5)
- *2 Recommendable Value 3.5 ~ 4.5 N•m (M6)



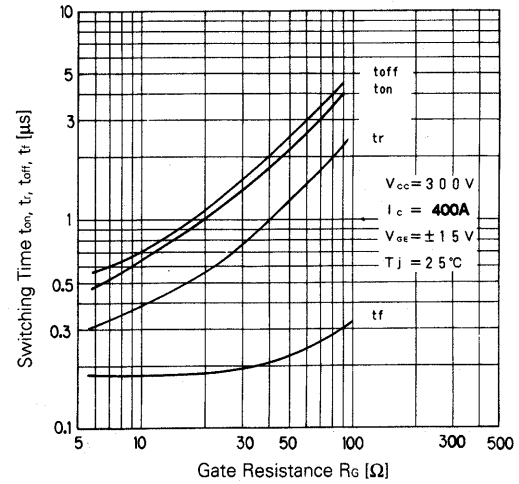
Collector Current vs. Collector-Emmitter Voltage



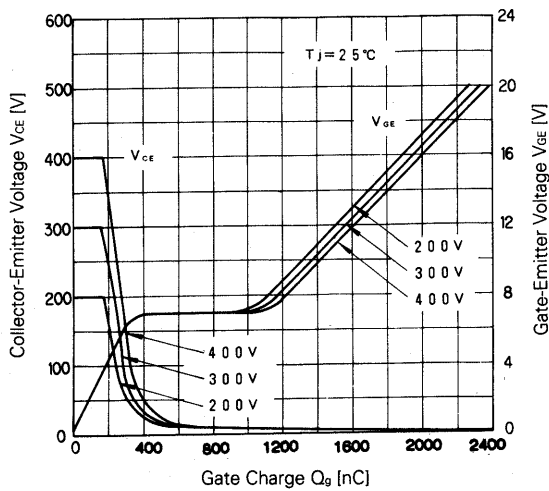
Collector-Emmitter Voltage vs. Gate-Emmitter Voltage



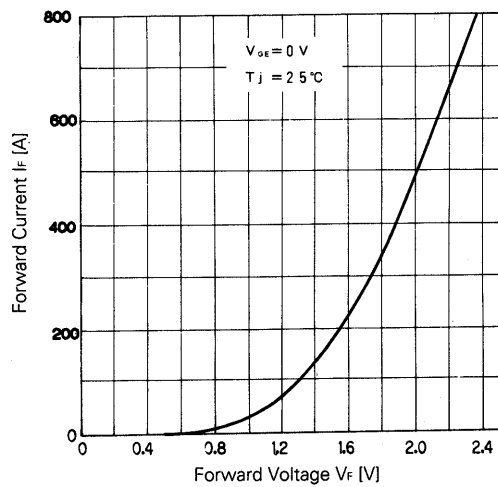
Switching Time



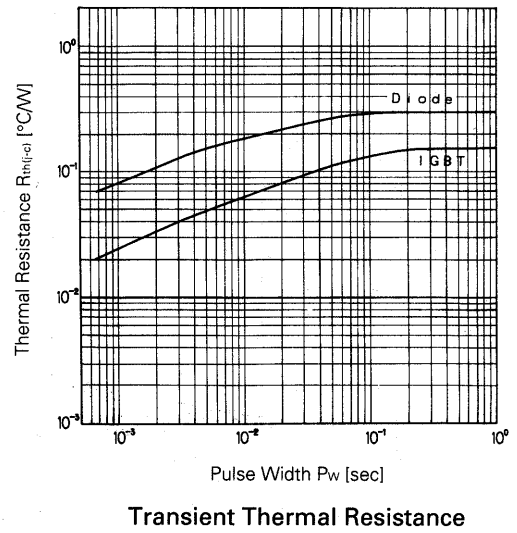
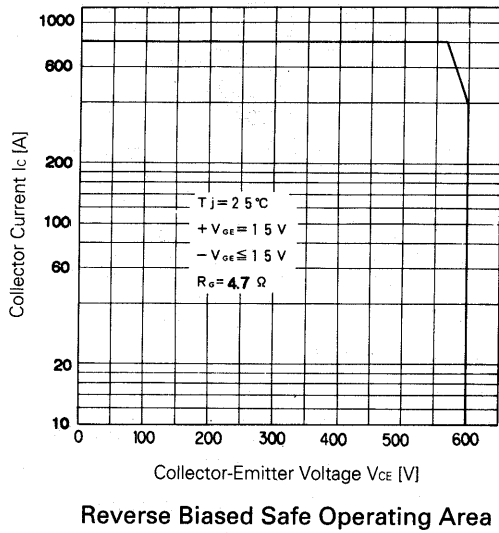
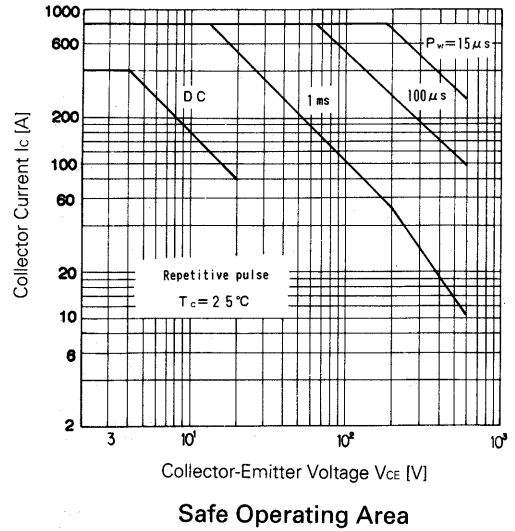
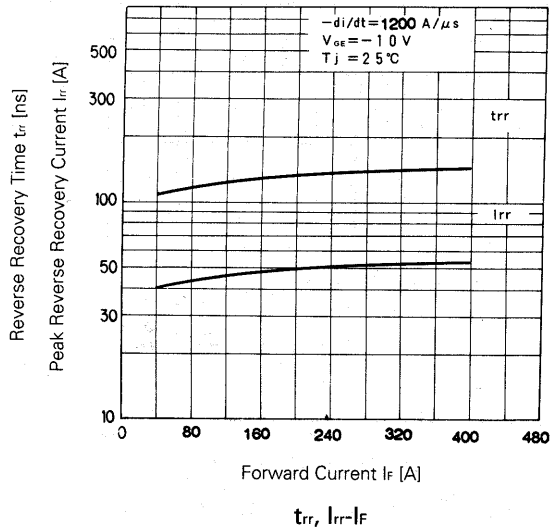
Switching Time-Gate Resistance



Dynamic Input Characteristic



Forward Voltage of Free Wheel Diode



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